L Number	Hits	Search Text	DB	Time stamp
1	4	(macro with embed\$4 with standard) and	USPAT;	2004/04/07
-	-	(@ad<19931227 or @rlad<19931227)	US-PGPUB;	17:43
			EPO; JPO;	
ì			DERWENT	0004/04/07
2	0	(macro with pitch with standard) and	USPAT;	2004/04/07
		(@ad<19931227 or @rlad<19931227)	US-PGPUB;	17:43
			EPO; JPO; DERWENT	
	_		USPAT;	2004/04/07
3	0	((macro with standard) same pitch) and (@ad<19931227)	US-PGPUB;	17:43
		(@ad<19931227 Of @ffad<19931227)	EPO; JPO;	- /
			DERWENT	Į
4	15	((macro with standard) same pitch)	USPAT;	2004/04/07
4	13	(macro wrest beastants, same is	US-PGPUB;	18:02
	ì		EPO; JPO;	i
			DERWENT	
5	2	5539224.pn.	USPAT;	2004/04/07
		•	US-PGPUB;	18:05
'			EPO; JPO;	1
			DERWENT	2004/04/07
6	2	5342794.pn.	USPAT; US-PGPUB;	18:07
			EPO; JPO;	10.07
	i l		DERWENT	i
_	[_ [2461261	USPAT;	2004/04/07
7	3	3461361.pn.	US-PGPUB;	18:08
			EPO; JPO;	
			DERWENT	
8	2	5286518.pn.	USPAT;	2004/04/07
B		3200310.pm.	US-PGPUB;	18:12
			EPO; JPO;	1
			DERWENT	
9	2	5410173.pn.	USPAT;	2004/04/07
	_	•	US-PGPUB;	18:13
			EPO; JPO;	
			DERWENT	2004/04/07
10	2	4742383.pn.	USPAT; US-PGPUB;	18:14
			EPO; JPO;	10.14
			DERWENT	ì
		5212070	USPAT;	2004/04/07
11	2	5313079.pn.	US-PGPUB;	18:15
			EPO; JPO;	
			DERWENT	l .
_	17993	((n adj channel) or "n-channel") same ((p	USPAT;	2004/04/07
-	1,903	adj channel) or "p-channel") same drain	US-PGPUB;	12:15
	ł	same gate	EPO; JPO;	
			DERWENT	0004/04/05
_	13832	((n adj channel) or "n-channel") same ((p	USPAT;	2004/04/06
		adj channel) or "p-channel") same (drain	US-PGPUB;	17:17
		with gate)	EPO; JPO;	
		1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1	DERWENT USPAT;	2004/04/06
-	3587	(((n adj channel) or "n-channel") same	US-PGPUB;	17:17
		((p adj channel) or "p-channel") same	EPO; JPO;	-/
		(drain with gate)) same inverter	DERWENT	
1	7.0	((((n adj channel) or "n-channel") same	USPAT;	2004/04/06
	72	(((n adj channel) of n-channel) same	US-PGPUB;	17:17
-	1	(drain with gate)) same inverter) same	EPO; JPO;	
	1	polysilicon	DERWENT	
1_	659	((n adi channel) or "n-channel") same ((p	USPAT;	2004/04/06
-		adi channel) or "p-channel") same (drain	US-PGPUB;	17:17
		with gate with polysilicon)	EPO; JPO;	
			DERWENT	0004/01/05
-	41	(((n adj channel) or "n-channel") same	USPAT;	2004/04/06
		((p adi channel) or "p-channel") same	US-PGPUB;	17:17
		(drain with gate with polysilicon)) same	EPO; JPO;	1
		inverter	DERWENT	1

				2004/04/06
-	20		USPAT; US-PGPUB;	17:33
		1 (t) att Chamies / Or P Chamis	EPO; JPO;	17.55
		Idiati with date with porjuration,	DERWENT	
1		Inverter, and (ead(1999122, 01	DERWENT	
	17	<pre>@rlad<19931227) ((n adj channel) or "n-channel") with ((p)</pre>	USPAT;	2004/04/06
-	1/	adj channel) or "p-channel") with drain	US-PGPUB;	17:54
ļ	!	with gate with "same" with silicon	EPO; JPO;	
		with gate with band near	DERWENT	
_ i	9	(((n adj channel) or "n-channel") with	USPAT;	2004/04/06
-		((p adi channel) or "p-channel") with	US-PGPUB;	17:39
		drain with gate with "same" with silicon)	EPO; JPO;	
ì		and (@ad<19931227 or @rlad<19931227)	DERWENT	2004/04/06
_	0	(trace with gate with coplanar) and	USPAT;	18:04
		(@ad<19931227 or @rlad<19931227)	US-PGPUB; EPO; JPO;	10.04
1			DERWENT	
ŀ		ill water with gonlanar	USPAT;	2004/04/06
- [10	trace with gate with coplanar	US-PGPUB;	17:39
	1		EPO; JPO;	
1			DERWENT	
Į	27	((n adj channel) or "n-channel") with ((p	USPAT;	2004/04/06
-	41	adi channel) or "p-channel") same (drain)	US-PGPUB;	18:02
	ļ	with gate with "same" with silicon with	EPO; JPO;	
		form\$3)	DERWENT	2004/04/06
_	17	((n adi channel) or "n-channel") with	USPAT;	2004/04/06
}	[//p adi channel) or "p-channel") same	US-PGPUB;	17:55
		(drain with gate with "same" with silicon	EPO; JPO;	
	1	with form\$3)) and (@ad<19931227 or	DERWENT	
	i	@rlad<19931227)	USPAT;	2004/04/06
-	4	drain with gate with "same" with silicon	US-PGPUB;	18:03
		with elevated	EPO; JPO;	10.00
	ļ		DERWENT	
	120	drain with gate with silicon with	USPAT;	2004/04/06
-	130	elevated	US-PGPUB;	18:13
		l	EPO; JPO;	Ì
	Į.		DERWENT	
_	24	(drain with gate with silicon with	USPAT;	2004/04/07
_		elevated) and (@ad<19931227 or	US-PGPUB;	12:17
		@rlad<19931227)	EPO; JPO;	
			DERWENT	2004/04/06
_	11	((drain with gate with silicon with	USPAT;	18:05
		elevated) and (@ad<19931227 or	US-PGPUB; EPO; JPO;	10.03
		Grlad<19931227)) and ((n adj channel) or	DERWENT	
		"n-channel") same ((p adj channel) or	DUMBINI	
		<pre>"p-channel") drain with gate with silicon with raised</pre>	USPAT;	2004/04/06
_	113	drain with gate with Silicon with larged	US-PGPUB;	18:14
			EPO; JPO;	
			DERWENT	
	17	(drain with gate with silicon with	USPAT;	2004/04/06
-	'	raised) and (@ad<19931227 or	US-PGPUB;	18:24
		@rlad<19931227)	EPO; JPO;	
			DERWENT	2004/04/07
_	1058	((n adj channel) or "n-channel") same ((p	USPAT;	2004/04/07
		adi channel) or "p-channel") and (drain	US-PGPUB;	13:02
	1	with "same" with gate with layer)	EPO; JPO;	
			DERWENT	2004/04/07
_	326	(((n adj channel) or "n-channel") same	USPAT; US-PGPUB;	12:17
		((p adj channel) or "p-channel") and	EPO; JPO;	14.1
i	1	(drain with "same" with gate with layer)) and (@ad<19931227 or @rlad<19931227)	DERWENT	
	l .	land (@ad<1993122) or @rlad<1993144/)		2004/04/07
		did (cad 1 1 1 1 1 1 1 1		, = / / - /
_	198	(n adi channel) or "n-channel") same ((p	USPAT;	
_	198	((n adj channel) or "n-channel") same ((p adj channel) or "p-channel") same (drain	US-PGPUB;	12:17
-	198	(n adi channel) or "n-channel") same ((p	US-PGPUB; EPO; JPO;	
		<pre>((n adj channel) or "n-channel") same ((p adj channel) or "p-channel") same (drain with "same" with gate with layer)</pre>	US-PGPUB;	
-	198	<pre>((n adj channel) or "n-channel") same ((p adj channel) or "p-channel") same (drain with "same" with gate with layer) (((n adj channel) or "n-channel") same</pre>	US-PGPUB; EPO; JPO; DERWENT	12:17
		<pre>((n adj channel) or "n-channel") same ((p adj channel) or "p-channel") same (drain with "same" with gate with layer)</pre>	US-PGPUB; EPO; JPO; DERWENT USPAT;	12:17 2004/04/07 12:52

				0004/04/07
_	16994	etch\$3 with gate with substrate	USPAT;	2004/04/07 12:53
			US-PGPUB; EPO; JPO;	12:53
			DERWENT	1
		(etch\$3 with gate with substrate) with	USPAT;	2004/04/07
-	0	from	US-PGPUB;	12:51
	ì l	Trom	EPO; JPO;	
			DERWENT	
_ '	269	(etch\$3 with gate with substrate) same	USPAT;	2004/04/07
		(drain with gate with "same" with layer)	US-PGPUB;	12:54
	1		EPO; JPO;	
			DERWENT	2024/04/07
-	57	((etch\$3 with gate with substrate) same	USPAT;	2004/04/07
ļ		(drain with gate with "same" with layer))	US-PGPUB; EPO; JPO;	12:54
	1	and (@ad<19931227 or @rlad<19931227)	DERWENT	
		form\$3 with gate with (substrate near2	USPAT;	2004/04/07
_	2888		US-PGPUB;	12:54
1		etch\$3)	EPO; JPO;	
		*	DERWENT	
	25	(form\$3 with gate with (substrate near2	USPAT;	2004/04/07
_	23	etch\$3)) same (drain with gate with	US-PGPUB;	14:50
		"same" with layer)	EPO; JPO;	
			DERWENT	2004/04/07
-	5	((form\$3 with gate with (substrate near2	USPAT;	2004/04/07
		etch\$3)) same (drain with gate with	US-PGPUB; EPO; JPO;	13:02
	1	"same" with layer)) and (@ad<19931227 or	DERWENT	
		@rlad<19931227)	USPAT;	2004/04/07
-	217	inverter with trace	US-PGPUB;	13:01
ì			EPO; JPO;	Ì
			DERWENT	
_	4	((inverter with trace) and ((n adj	USPAT;	2004/04/07
_	•	channel) or "n-channel") same ((p adj	US-PGPUB;	13:32
		channel) or "p-channel")) and	EPO; JPO;	
ľ		(@ad<19931227 or @rlad<19931227)	DERWENT	2004/04/07
_	25	(inverter with trace) and ((n adj	USPAT; US-PGPUB;	13:07
1		channel) or "n-channel") same ((p adj	EPO; JPO;	13.07
1	ļ	channel) or "p-channel")	DERWENT	
	105	trace with connect\$3 with drain	USPAT;	2004/04/07
-	125	Clace with connector with drain	US-PGPUB;	13:31
	1		EPO; JPO;	
			DERWENT	
1_	26	(trace with connect\$3 with drain) and	USPAT;	2004/04/07
		(@ad<19931227 or @rlad<19931227)	US-PGPUB;	14:51
			EPO; JPO;	
1		1	DERWENT USPAT	2004/04/07
-	3	("4181860" "4387433" "4433384").PN.	OSFAI	14:44
		connect\$3 with drain with "adjacent" with	USPAT;	2004/04/07
-	1694	transistor	US-PGPUB;	14:49
		CEGIISTSCOT	EPO; JPO;	
			DERWENT	
_	33	(connect\$3 with drain with "adjacent"	USPAT;	2004/04/07
		with transistor) same (drain with gate	US-PGPUB;	14:51
1		with "same" with layer)	EPO; JPO;	
			DERWENT	2004/04/07
-	15	((connect\$3 with drain with "adjacent"	USPAT; US-PGPUB;	15:08
	\	with transistor) same (drain with gate	EPO; JPO;	1 20.00
		with "same" with layer)) and (@ad<19931227 or @rlad<19931227)	DERWENT	
	29	1	USPAT;	2004/04/07
] -	29	with "same" with layer	US-PGPUB;	15:13
			EPO; JPO;	
	1		DERWENT	0004/04/07
-	9	(cmos with gate with drain with form\$3	USPAT;	2004/04/07
		with "same" with layer) and (@ad<19931227	US-PGPUB;	15:14
		or @rlad<19931227)	EPO; JPO; DERWENT	
	İ		DEKMENT	1

		(the sith dealer with	USPAT;	2004/04/07
_	18	inverter same (gate with drain with	US-PGPUB;	15:14
		form\$3 with "same" with layer)		13.11
			EPO; JPO;	
Ì			DERWENT	
	8	(inverter same (gate with drain with	USPAT;	2004/04/07
-	١	form\$3 with "same" with layer)) and	US-PGPUB;	16:05
}	ļ	(@ad<19931227 or @rlad<19931227)	EPO; JPO;	
		(ead(19931227 of effect)	DERWENT	<u> </u>
	1	/singt with layor with	USPAT;	2004/04/07
-	0	(macro same (first with layer with	US-PGPUB;	16:06
		metallization) same (second with layer	EPO; JPO;	
		with metallization with interconnect with	DERWENT	
		macro)) and (@ad<19931227 or	DEVMENT	ļ
		@rlad<19931227)	**********	2004/04/07
_	2	(macro same ((first or second) with layer	USPAT;	
	.	with metallization) same (interconnect	US-PGPUB;	16:08
	ľ	with macro)) and (@ad<19931227 or	EPO; JPO;	
ļ	Į.	@rlad<19931227)	DERWENT	1
		1	USPAT;	2004/04/07
-	4	with metallization) and (interconnect	US-PGPUB;	17:36
		With metallization, and (interconnect	EPO; JPO;	
		with macro)) and (@ad<19931227 or	DERWENT	
l l	1	@rlad<19931227)	DELLATE	

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